UNITED STATES PATENT AND TRADEMARK OFFICE CERTIFICATE OF CORRECTION

PATENT NO. : 7,638,828 B2 Page 1 of 1

APPLICATION NO.: 10/542041

DATED : December 29, 2009 INVENTOR(S) : Jean-Pierre Schoellkopf

It is certified that error appears in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Col. 1, line 8, should read: of capacitors associated with SRAM cells.

Column 7, claim 3, line 50, should read: and the second electrodes of which are a same coated region

Signed and Sealed this

Ninth Day of February, 2010

David J. Kappos Director of the United States Patent and Trademark Office